

AOZ6233

0.35Ω Low-Voltage Dual-SPDT Analog Switch

General Description

The AOZ6233 is a 0.35Ω low-voltage Dual Single Pole Double Throw (SPDT) analog switch. The AOZ6233 operates from a single 1.65V to 3.6V supply. It features an ultra-low On Resistance of 0.35Ω at a +2.7V supply and 25°C. The AOZ6233 is designed for break-before-make operation.

Features

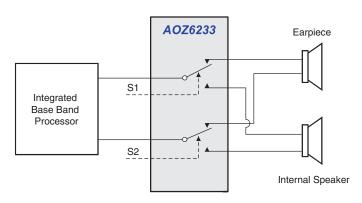
- Typical 0.35Ω On Resistance (R_{ON}) for +2.7V supply
- 0.15Ω maximum R_{ON} flatness for +2.7V supply
- 1.6mm x 2.1mm QFN package
- Broad V_{CC} operating range
- Low THD (0.02% typical for 32Ω load)
- High current handling capability (350mA continuous current under 3.3V supply)

Applications

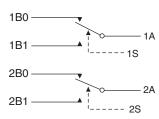
- Cell phone
- PDA
- Portable media player



Typical Application



Pin Configuration





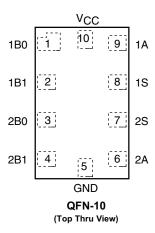
Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ6233QI	-40°C to +85°C	QFN-10	RoHS Compliant
			Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

Pin Configuration



Pin Description

Pin Name	Function
1A, 2A, 1B0, 1B1, 2B0, 2B1	Data Ports
1S, 2S	Control Input

Truth Table

Logic Input	Function
0	B0 Connected to A
1	B1 Connected to A



Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +5.5V
Vs	Switch Voltage ⁽¹⁾	-0.5 to V _{CC} + 0.5V
V _{IN}	Input Voltage ⁽¹⁾	-0.5 to V _{CC}
I _{IK}	Minimum Input Diode Current ⁽²⁾	-50mA
I _{SW}	Switch Current	350mA
I _{SWPEAK}	Peak Switch Current (Pulsed at 1ms duration, <10% Duty Cycle)	500mA
T _{STG}	Storage Temperature Range	-65°C to +150°C
TJ	Maximum Junction Temperature	+150°C
T _L	Lead Temperature (Soldering, 10 seconds)	+260°C
ESD	Human Body Model	8000V
	Charged Device Model	1000V

Recommend Operating Ratings

The device is not guaranteed to operate beyond the Maximum Operating Ratings.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	1.65V to +3.6V
V _{IN}	Control Input Voltage ⁽³⁾	0V to V _{CC}
V _{SW}	Switch Input Voltage	0V to V _{CC}
T _A	Operating Temperature	-40°C to +85°C

Notes:

- 1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.
- 2. Negative current should not exceed minimum negative value.
- 3. Unused inputs must be held HIGH or LOW. They may not float.



DC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{CC} (V)	Min.	Тур.	Max.	Units
V _{IH}	Input Voltage HIGH		2.7 to 3.6	2.0			V
			2.3 to 2.7	1.7			
			1.65 to 1.95	0.65 x V _{CC}			
V _{IL}	Input Voltage LOW		2.7 to 3.6			0.8	V
			2.3 to 2.7			0.7	
			1.65 to 1.95			0.35 x V _{CC}	
I _{IN}	Control Input Leakage	V _{IN} = 0V to V _{CC}	1.65 to 3.6	-0.5		0.5	μA
I _{NO(OFF)} , I _{NC(OFF)}	Off-Leakage Current of Port nB ₀ and nB ₁	nA = 0.3V, 3.3V, nB0 or nB1 = 0.3V, 3.3V or floating	3.6	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
I _{A(ON)}	On Leakage Current of Port 1A and 2A	nA = 0.3V, 3.3V, nB0 or nB1 = 0.3V, 3.3V or floating	3.6	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
R _{ON}	Switch On Resistance ⁽⁴⁾ See Figure 1	I _{OUT} = 100mA, nB0 or nB ₁ = 0V, 0.7V, 2.0V, 2.7V	2.7		0.35	0.60	Ω
		I _{OUT} = 100mA, nB0 or nB1 = 0V, 0.7V, 1.6V, 2.3V	2.3		0.40	0.70	
		I _{OUT} = 100mA, nB0 or nB1 = 0.8V	1.65		1.0	3.0	
ΔR _{ON}	On Resistance Matching	I _{OUT} = 100mA, nB0 or	2.7		0.040	0.075	Ω
	Between Channels ⁽⁵⁾	nB1 = 0.7V	2.3		0.040	0.080	
			1.65		0.1		
R _{FLAT(ON)}	On Resistance Flatness ⁽⁶⁾	I _{OUT} = 100mA, nB0 or	2.7			0.15	Ω
(,		nB1 = 0V to V _{CC}	2.3			0.3	1
			1.65		1.6		
I _{CC}	Quiescent Supply Current	V _{IN} = 0V or V _{CC} , I _{OUT} = 0A	3.6	-500		500	nA
Ісст	Increase in I _{CC} per Input	V _{IN} = 1.8V	3.6		75		μΑ
		V _{IN} = 2.6V			5		

Notes:

- 4. On resistance is determined by the voltage drop between A and B pins at the indicated current through the switch.
- 5. ΔR_{ON} = R_{ONmax} R_{ONmin} measured at identical V_{CC} , temperature, and voltage.
- $6.\ Flatness\ is\ defined\ as\ the\ difference\ between\ the\ maximum\ and\ minimum\ value\ of\ R_{ON}\ over\ the\ specified\ range\ of\ conditions.$

Rev. 2.1 February 2012 **www.aosmd.com** Page 4 of 11



AC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{CC} (V)	Min.	Тур.	Max.	Units
t _{ON}	Turn-On Time	nB0 or nB1 = 1.5V, $R_L = 50\Omega$,	2.7 to 3.6		40.0	50.0	ns
		$C_L = 35pF$	2.3 to 2.7		50.0	55.0	
			1.65 to 1.95		75.0	90.0	
t _{OFF}	Turn-Off Time	nB0 or nB1 = 1.5V, $R_L = 50\Omega$,	2.7 to 3.6		10.0	25.0	ns
		$C_L = 35pF$	2.3 to 2.7		20.0	25.0	
			1.65 to 1.95		50.0	55.0	
t _{BBM}	Break-Before-Make Time	nB0 or nB1 = 1.5V, $R_L = 50Ω$,	2.7 to 3.6	2.0	17.0		ns
		$C_L = 35pF$	2.3 to 2.7	2.0	15.0		
			1.65 to 1.95	2.0	12.0		
Q	Charge Injection	C_L = 100pF, V_{GEN} = 0V, R_{GEN} = 0 Ω	1.65 to 3.6		9.0		pC
OIRR	Off Isolation	$f = 100kHz$, $R_L = 50\Omega$, $C_L = 5pF$ (Stray)	1.65 to 3.6		-95		dB
Xtalk	Crosstalk	$f = 100kHz$, $R_L = 50\Omega$, $C_L = 5pF$ (Stray)	1.65 to 3.6		-95		dB
BW	-3dB Bandwidth	$R_L = 50\Omega$	1.65 to 3.6		45.0		MHz
THD	Total Harmonic Distortion	$R_L = 32\Omega$, $V_{IN} = 2V_{pk-pk}$, $f = 20Hz$ to $20kHz$	2.7 to 3.6		0.024		%
		$R_L = 32\Omega$, $V_{IN} = 1.5V_{pk-pk}$, $f = 20Hz$ to $20kHz$	2.3 to 2.7		0.015		
		$R_L = 32\Omega$, $V_{IN} = 1.2V_{pk-pk}$, f = 20Hz to 20kHz	1.65 to 1.95		0.35		

Capacitance

Symbol	Parameter	Conditions	V _{CC} (V)	Min.	Тур.	Max.	Units
C _{IN}	Control Pin Input Capacitance	f = 1MHz	0.0		4		pF
C _{OFF}	B Port Off Capacitance	f = 1MHz	3.3		22		pF
C _{ON}	A Port On Capacitance	f = 1MHz	3.3		140		pF

Rev. 2.1 February 2012 **www.aosmd.com** Page 5 of 11



Typical Performance Characteristics

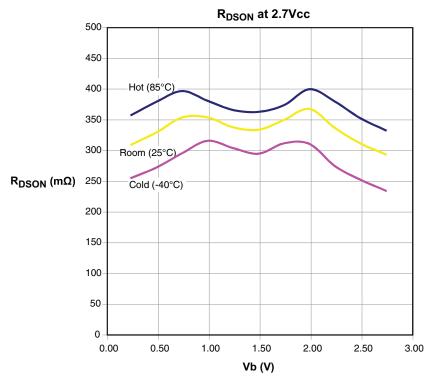


Figure 1. Switch On Resistance



AC Loading and Waveforms

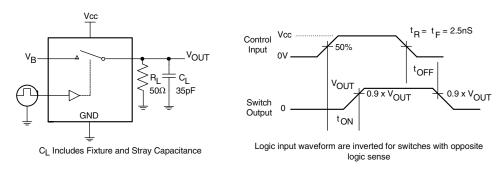


Figure 1. Turn-On/Turn-Off Timing

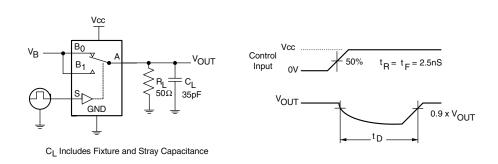


Figure 2. Break-Before-Make Timing`

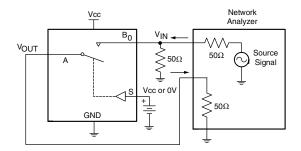


Figure 3. Off Isolation

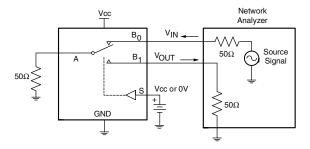


Figure 4. Crosstalk



AC Loading and Waveforms (continued)

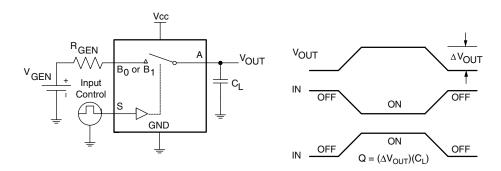


Figure 5. Charge Injection

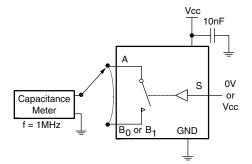


Figure 6. ON/Off Capacitance Measurement

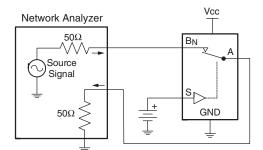


Figure 7. Bandwidth

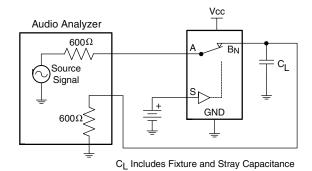
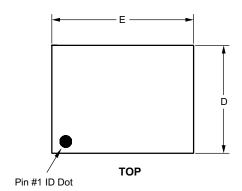
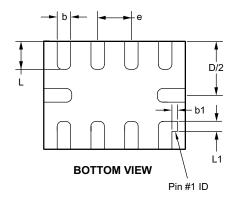


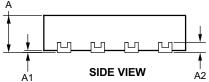
Figure 8. Harmonic Distortion

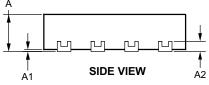


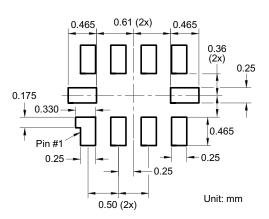
Package Dimensions, QFN-10











Dimensions in millimeters

Symbols	Min.	Nom.	Max.			
Α	0.50	0.55	0.60			
A1	0.00		0.05			
A2	0.	152 REF	=.			
b	0.15	0.20	0.25			
b1	0.08 REF.					
D	1.55	1.60	1.65			
E	2.05	2.10	2.15			
е	().50 BSC	;			
L	0.365	0.415	0.465			
L1	0.15 REF.					

Dimensions in inches

Symbols	Min.	Nom.	Max.					
Α	0.020	0.022	0.024					
A1	0.00	_	0.002					
A2	0.006 REF.							
b	0.006	0.008	0.010					
b1	0.	.003 REF	=.					
D	0.061	0.063	0.065					
Е	0.081	0.083	0.085					
е	0	.020 BS	С					
L	0.014	0.016	0.018					
L1	0.	.006 REF	=.					

Note:

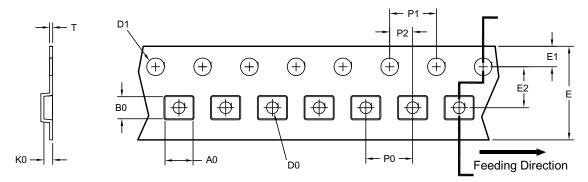
1. Controlling dimension is millimeter. Converted inch dimensions are not necessarily exact.

Rev. 2.1 February 2012 www.aosmd.com Page 9 of 11



Tape and Reel Dimensions, QFN-10

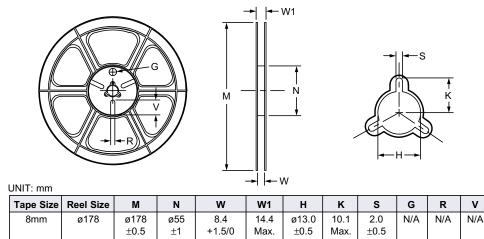
Carrier Tape



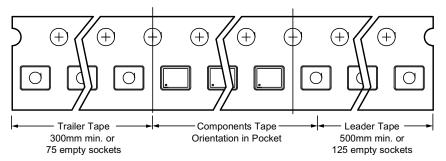
UNIT: mm

Package	A0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
QFN 2.1 x 1.6	0.76	1.21	0.53	0.50	1.5	8.00	1.75	3.50	4.00	4.00	2.00	0.254
(8mm)	±0.05	±0.05	±0.05	±0.05	±0.10	+0.30/-0.10	±0.10	±0.05	±0.10	±0.10	±0.05	±0.02

Reel



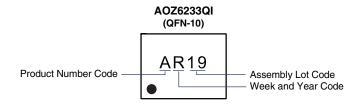
Leader/Trailer and Orientation



Rev. 2.1 February 2012 **www.aosmd.com** Page 10 of 11



Part Marking



This datasheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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Rev. 2.1 February 2012 **www.aosmd.com** Page 11 of 11

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